

Substitute specification**Remarks:**

The following substitute specification is current effective the date of the current Office action and reflects amendments to paragraphs [0013], [0023], [0025], and
5 [0027] previously acknowledged by the Examiner. The un-entered amendments filed on 08/16/2006 to paragraphs [0012] and [0022] are not reflected in the substitute specification. Current amendments to the substitute specification requested in this paper are listed in the "Amendments to the Specification" section of this response.

Title

PIXEL STRUCTURE OF ACTIVE MATRIX DISPLAY DEVICE

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Background of Invention

[0001] 1. Field of the Invention

[0002] The present invention relates to a pixel structure of an active matrix display
10 device, and more specifically, to a pixel structure of an organic light emitting display device.

[0003] 2. Description of the Prior Art

15 [0004] In various types of flat panel displays, since an organic light emitting diode (OLED) has many beneficial characteristics, such as having a spontaneous light source, a wide viewing angle, a high response velocity, full-color, a simpler structure, a wide operating temperature, and power saving properties, the OLED has been used
20 extensively in small and medium scale portable display fields.

[0005] Please refer to Fig.1. Fig.1 is a schematic diagram of a prior art organic light emitting display device 10. The organic light emitting display device 10 comprises a display panel 12, a scanning line driving

circuit 14, and a data line driving circuit 16. The display panel 12 includes a plurality of scanning lines 18 (i.e. SL_1 - SL_m), a plurality of data lines 20 (i.e. DL_1 - DL_n) that are perpendicular to the scanning lines 18, and a plurality of pixels 22 connected to the scanning lines 18 and the data lines 20. Furthermore, the scanning line driving circuit 14 and the data line driving circuit 16 input respective signals to the scanning lines 18 and the data lines 20. Accordingly, each of the pixels 22 can receive corresponding signals via the scanning lines 18 and the data lines 20, and can display a gray level according to the corresponding signals. The organic light emitting display device 10 can therefore display an image that is composed of the gray levels displayed by the pixels 22.

[0006] Please refer to Fig.2. Fig.2 is a circuit diagram of one of the pixels 22 shown in Fig.1. As shown in Fig.2, the pixel 22 comprises two thin film transistors 24 and 26, a storage capacitor 28, and an organic light emitting diode 30. The thin film transistor 24 includes a gate electrode 24a electrically connected to the scanning line 18, a drain electrode 24b electrically connected to the data line 20, and a source electrode 24c. Additionally, the thin film transistor 26 comprises a gate electrode 26a electrically connected to the source electrode 24c and one end of the storage capacitor 28, a source electrode 26c electrically connected to an external power supply V_{dd} , and a drain electrode 26b electrically connected to an anode 30a of the organic light emitting

diode 30 whose cathode 30b is grounded.

[0007] As shown in Fig.2, when the pixel 22 is on its operation mode, the scanning line driving circuit 14 inputs a scanning signal into the gate electrode 24a of the thin film transistor 24 via the scanning line 18 for turning on the thin film transistor 24. Thereafter, the data line driving circuit 16 inputs a corresponding data signal into the drain electrode 24b of the thin film transistor 24 through the data line 20 for turning on the thin film transistor 26. At the same time, the external power source V_{dd} provides a driving current to the organic light emitting diode 30 through the thin film transistor 26. Then, the driving current would make the organic light emitting diode 30 radiate light beams to display a corresponding gray level that is varied according to a quantity of the driving current.

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[0008] Please refer to Fig.3 and Fig.4. Fig.3 is a cross-sectional view of the organic light emitting diode 30 shown in Fig.2. Fig.4 is a top view of the organic light emitting diode shown in Fig.3. As shown in Fig.3, the organic light emitting diode 30 mainly comprises a glass substrate 32, a transparent conductive layer 34 located on the glass substrate 32 for being the anode 30a of the organic light emitting diode 30, a composite layer 36 located on the transparent conductive layer 34, and a metal layer 38 located on the composite layer 36 for being the cathode 30b of the organic light emitting diode 30. Additionally, the composite layer 36

is composed of a hole transporting layer 36a, a light emitting layer 36b, and an electron transporting layer 36c. The transparent conductive layer 34 is made from indium tin oxide (ITO) or indium zinc oxide (IZO), while the metal layer 38 is composed of magnesium (Mg), aluminum (Al), or an alloy of lithium (Li) and silver (Ag).

[0009] Unfortunately, an electrical shortage always occurs between the metal layer 38 and the transparent conductive layer 34 due to process errors or other factors. For example, a spike of the metal layer 38 is formed due to process errors and always perforates the composite layer 36 to contact with the transparent conductive layer 34, as is indicated by an array A in Fig.3. Alternatively, an uneven surface of the transparent conductive layer 34 also causes the transparent conductive layer 34 to contact with the metal layer 38, as is indicated by an array B in Fig.3. Because the resistances of the electrical shortages, indicated by the arrays A and B, are approximately equal to thousands of ohms ($K\Omega$) and the resistance of the organic light emitting diode 30 is equal to millions of ohms ($M\Omega$), most driving current will flow through not the organic light emitting diode 30 but the electrical shortages, indicated by the arrays A and B. Therefore, the organic light emitting diode 30 cannot radiate light beams, which leads to forming a defect on the organic light emitting display device 10.

[0010] As shown in Fig.4, laser beams are always utilized in a prior art

method to cut conjunction portions between the organic light emitting diode 30 and the electrical shortages, indicated by the arrays A and B. However, the laser beams usually cause the metal layer 38 surrounding the electrical shortages to contact with the transparent conductive layer 34, which leads to other electrical shortages. Therefore, the laser beams cannot effectively repair the defects on the organic light emitting display device 10. Furthermore, the prior art method requires operators to find out the defects first, and then utilizes the laser beams to repair the defects, so that the prior art method requires a lot of time and manpower, and is quite uneconomical.

Summary of Invention

[0011] It is therefore a primary objective of the claimed invention to provide a pixel structure of an organic light emitting display device to solve the above-mentioned problem.

[0012] According to the claimed invention, a pixel structure of an active matrix display device is provided. The pixel structure includes a storage capacitor, a first active device having a first end electrically connected to a scanning line, a second end electrically connected to a data line, a third end electrically connected to the storage capacitor, and a plurality of active-type light emitting devices electrically connected in parallel with each other between a source of first potential, a source of second

potential, and the third end.

[0013] It is an advantage over the prior art that the claimed invention provides a pixel comprising a plurality of active-type light emitting devices connected in parallel with each other. Each active-type light emitting device is connected in series to an active device that is used to supply a driving current to the light emitting device. Therefore, when an electrical shortage occurs in one of the active-type light emitting devices of a pixel, the pixel still can display an image via the other active-type light emitting devices of the pixel. Therefore, it is unnecessary to utilize laser beams to repair defects, so that the production time can be saved and the yield can be effectively improved.

[0014] These and other objectives of the present invention will no doubt become obvious to those of ordinary skill in the art after reading the following detailed description of the preferred embodiment, which is illustrated in the multiple figures and drawings.

Brief Description of Drawings

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[0015] Fig.1 is a schematic diagram of a prior art organic light emitting display device.

[0016] Fig.2 is a circuit diagram of a pixel shown in Fig.1.

[0017] Fig.3 is a cross-sectional view of the organic light emitting diode

shown in Fig.2.

[0018] Fig.4 is a top view of the organic light emitting diode shown in Fig.3.

[0019] Fig.5 is a schematic diagram of an active matrix display device
5 according to the present invention.

[0020] Fig.6 is a circuit diagram of a pixel shown in Fig.5.

Detailed Description

10 [0021] Please refer to Fig.5. Fig.5 is a schematic diagram of an active matrix display device according to the present invention. The active matrix display device 40 comprises a display panel 42, a scanning line driving circuit 44, and a data line driving circuit 46. The display panel 42 includes a plurality of scanning lines 48 (i.e. SL_1 - SL_m), a plurality of
15 data lines 50 (i.e. DL_1 - DL_n) that are perpendicular to the scanning lines 48, and a plurality of pixels 52 that are electrically connected to the scanning lines 48 and the data lines 50. The scanning line driving circuit 44 and the data line driving circuit 46 respectively input signals to the scanning lines 48 and the data lines 50. Accordingly, each of the pixels
20 52 can receive corresponding signals via the scanning lines 48 and the data lines 50, and can display a gray level according to the corresponding signals. The organic light emitting display device 40 can therefore display an image that is composed of the gray levels displayed by the pixels 52.

[0022] Please refer to Fig.6. Fig.6 is a circuit diagram of one of the pixels 52 shown in Fig.5. As shown in Fig.6, the pixel 52 comprises a storage capacitor 54, an active device 56, and a plurality of active-type light emitting devices 58 that are connected in parallel with each other. Each active-type light emitting device 58 comprises an active device 60 (T_1 , T_2 , T_3 or T_4) and a light emitting device 62 (D_1 , D_2 , D_3 or D_4). The active-type light emitting devices 58 are electrically connected between a potential source 64, a potential source 66, and an end 54a of the storage capacitor 54. Additionally, the potential source 64 is used to supply a potential V_1 , while the potential source 66 is used to supply a potential V_2 that is a reference potential (ex. grounding potential) and is usually smaller than V_1 . Furthermore, each of the active devices 56, 60 is a thin film transistor or a complementary metal-oxide semiconductor (CMOS), and each of the light emitting devices 62 is an organic light emitting diode or a light emitting diode (LED).

[0023] In the preferred embodiment of the present invention, the active matrix display device 40 is an organic light emitting display device. Accordingly, each of the light emitting devices 62 is an organic light emitting diode, while the active device 56 is a thin film transistor comprising a gate electrode 56a electrically connected to the scanning line 48, a drain electrode 56b electrically connected to the data line 50, and a source electrode 56c electrically connected to the first electrode

54a of the storage capacitor 54. Furthermore, each of the active devices 60 is a thin film transistor comprising a gate electrode 60a as a switching end of the active device 60 that electrically connects to the source electrode 56c of the thin film transistor 56, a source electrode 60c electrically connected to the potential source 64, and a drain electrode 60b electrically connected to an anode 62a of the organic light emitting diode 62 whose cathode 62b is electrically connected to the potential source 66. In addition, a second electrode 54b of the storage capacitor 54 is electrically connected to the potential source 64, and moreover, the end second electrode 54b of the storage capacitor 54 also can be electrically connected to any other potential source capable of supplying a constant potential.

[0024] Additionally, the operating method of each pixel 52 is described as follows. Firstly, the scanning line driving circuit 44 inputs a scanning signal into the gate electrode 56a of the thin film transistor 56 through the scanning line 48. At the same time, the data line driving circuit 50 inputs a corresponding data signal into the drain electrode 56b of the thin film transistor 56 for turning on each of the thin film transistors 60 and charging the storage capacitor 54 to a first potential. Since each of the thin film transistors 60 is turned on, the potential source 64 supplies a driving current to each of the organic light emitting diodes 62 via the thin film transistors 60 to make the organic light emitting diodes 62 radiate light beams. When the thin film transistor 56 is turned off, the

storage capacitor 54 still has the first potential for maintaining each thin film transistor 60 on a conductible state so that the thin film transistors 60 can supply driving currents to the organic light emitting diodes 62 for making the organic light emitting diodes 62 radiate light beams continuously.

[0025] Additionally, if the anode 62a and the cathode 62b of the organic light emitting diodes D1 are contacted with each other due to process errors or other factors, an electrical storage occurs in the organic light emitting diodes 62 (ex. D1). Accordingly, the driving current supplied by the thin film transistor T1 cannot make the organic light emitting diodes D1 radiate light beams. Noticeably, since the pixel 52 shown in Fig.6 comprises four active-type light emitting devices 58 connected in parallel with each other, the thin film transistors T2, T3, and T4 still can supply driving currents to the organic light emitting diodes D2, D3, and D4. Therefore, the organic light emitting diodes D2, D3, and D4 still can radiate light beams to maintain the pixel 52 on a luminous state. In other words, as long as at least one of the organic light emitting diodes 62 in a pixel 52 is good, the pixel 52 can radiate light beams normally. Therefore, it is unnecessary to utilize laser beams to repair defects in the present invention. As a result, the yield can be effectively improved.

[0026] In brief, the present invention provides a pixel comprising a plurality of active-type light emitting devices connected in parallel with

each other. Each active-type light emitting device comprises an organic light emitting diode (or a light emitting diode), and a thin film transistor (or a CMOS) for supplying driving current to the organic light emitting diode. Additionally, a number of the active-type light emitting devices
5 is decided according to a dimension of the pixel. Theoretically, when a number of the active-type light emitting devices gets higher and higher, the gray level of the pixel would not be influenced as an electrical shortage occurs in the organic light emitting diode of the pixel. Furthermore, the electrical circuit of a pixel is not limited to the pixel
10 shown in Fig.6. That is, amounts and positions of the thin film transistor 56 and the storage capacitor 54 can be modified according to actual requirements.

[0027] In contrast to the prior art, the present invention provides a pixel
15 comprising a plurality of active-type light emitting devices connected in parallel with each other. Each active-type light emitting device is connected in series to an active device that is used to supply a driving current to the light emitting device. Therefore, when an electrical shortage occurs in one of the active-type light emitting devices of a
20 pixel, the pixel still can display an image via the other active-type light emitting devices of the pixel. Therefore, it is unnecessary to utilize laser beams to repair defects, so that the production time can be saved and the yield can be effectively improved.

[0028] Those skilled in the art will readily observe that numerous modifications and alterations of the device may be made while retaining the teachings of the invention. Accordingly, the above disclosure should be construed as limited only by the metes and bound of the appended

5 claims.